2SD1511

Silicon NPN epitaxial planer type darlington

For low-frequency output amplification

Features

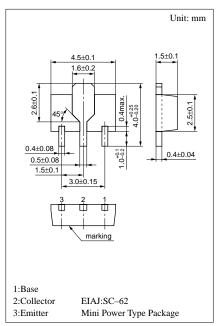
- Forward current transfer ratio h_{FE} is designed high, which is appropriate to the driver circuit of motors and printer bammer: h_{FE} = 4000 to 2000.
- A shunt resistor is omitted from the driver.
- Mini Power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

	-		
Parameter	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	100	V
Collector to emitter voltage	V _{CEO}	80	V
Emitter to base voltage	V _{EBO}	5	V
Peak collector current	I _{CP}	1.5	А
Collector current	I _C	1	А
Collector power dissipation	P_{C}^{*}	1	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 ~ +150	°C

Absolute Maximum Ratings (Ta=25°C)

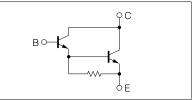
* Printed circuit board: Copper foil area of 1cm² or more, and the board thickness of 1.7mm for the collector portion

Electrical Characteristics (Ta=25°C)



Marking symbol : P

Internal Connection



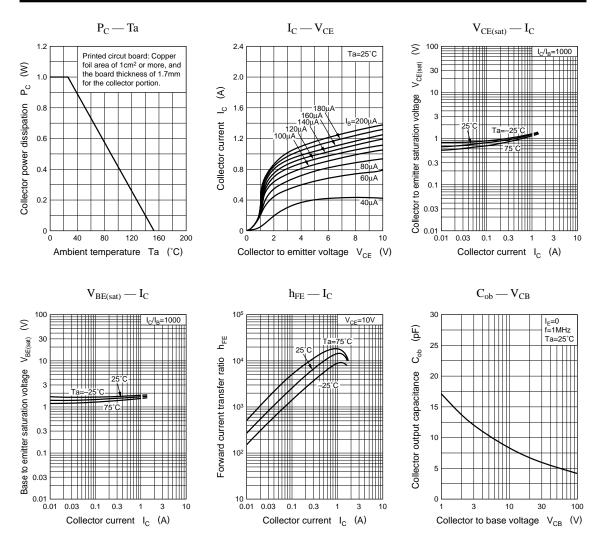
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = 25V, I_E = 0$			100	nA
Emitter cutoff current	I _{EBO}	$V_{EB} = 4V, I_C = 0$			100	nA
Collector to base voltage	V _{CBO}	$I_C = 100 \mu A, I_E = 0$	100			V
Collector to emitter voltage	V _{CEO}	$I_C = 1 m A$, $I_B = 0$	80			V
Emitter to base voltage	V _{EBO}	$I_E = 100 \mu A, I_C = 0$	5			V
Forward current transfer ratio	${h_{FE}}^{*1}$	$V_{CE} = 10V, I_C = 1A^{*2}$	4000		40000	
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 1.0 \text{A}, I_{\rm B} = 1.0 \text{mA}^{*2}$			1.8	V
Base to emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = 1.0 \text{A}, I_{\rm B} = 1.0 \text{mA}^{*2}$			2.2	V
Transition frequency	f _T	$V_{CB} = 10V, I_E = -50mA, f = 200MHz$		150		MHz

*2 Pulse measurement

*1hFE Rank classification

Rank	Q	R	S
h _{FE}	4000 ~ 10000	8000 ~ 20000	16000 ~ 40000
Marking Symbol	PQ	PR	PS

Transistor



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